Micropower Undervoltage Sensing Circuits

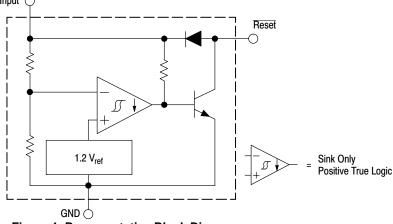
The MC34164 series are undervoltage sensing circuits specifically designed for use as reset controllers in portable microprocessor based systems where extended battery life is required. These devices offer the designer an economical solution for low voltage detection with a single external resistor. The MC34164 series features a bandgap reference, a comparator with precise thresholds and built–in hysteresis to prevent erratic reset operation, an open collector reset output capable of sinking in excess of 6.0 mA, and guaranteed operation down to 1.0 V input with extremely low standby current. The MC devices are packaged in 3–pin TO–92 (TO–226AA), micro size TSOP–5, 8–pin SOIC–8 and Micro8TM surface mount packages. The NCV device is packaged in SOIC–8.

Applications include direct monitoring of the 3.0 V or 5.0 V MPU/logic power supply used in appliance, automotive, consumer, and industrial equipment.

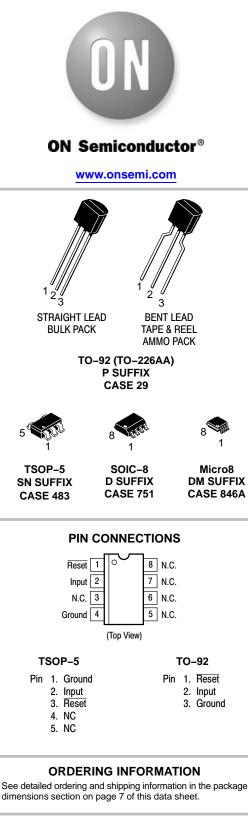
Features

- Temperature Compensated Reference
- Monitors 3.0 V (MC34164–3) or 5.0 V (MC34164–5) Power Supplies
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 6.0 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation With 1.0 V Input
- Extremely Low Standby Current: As Low as 9.0 µA
- Economical TO–92 (TO–226AA), TSOP–5, SOIC–8 and Micro8 Surface Mount Packages
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
- These Devices are Pb-Free and are RoHS Compliant

Input 🔿







DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 8 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V _{in}	-1.0 to 12	V
Reset Output Voltage	Vo	-1.0 to 12	V
Reset Output Sink Current	I _{Sink}	Internally Limited	mA
Clamp Diode Forward Current, Reset to Input Pin (Note 1)	IF	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Plastic Package Maximum Power Dissipation @ $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Air D Suffix, Plastic Package Maximum Power Dissipation @ $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Air DM Suffix, Plastic Package Maximum Power Dissipation @ $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Air	Ρ _D R _{θJA} Ρ _D R _{θJA} Ρ _D R _{θJA}	700 178 700 178 520 240	mW °C/W ™W °C/W mW °C/W
Operating Junction Temperature	ТJ	+150	°C
Operating Ambient Temperature Range MC34164 Series MC33164 Series, NCV33164	T _A	0 to +70 - 40 to +125	°C
Storage Temperature Range	T _{stg}	– 65 to +150	°C
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM)	ESD	4000 200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

MC34164-3, MC33164-3 SERIES, NCV33164-3

ELECTRICAL CHARACTERISTICS (For typical values $T_A = 25^{\circ}C$, for min/max values T_A is the operating ambient temperature range that applies [Notes 2 & 3], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
COMPARATOR					
Threshold Voltage High State Output (V _{in} Increasing) Low State Output (V _{in} Decreasing) Hysteresis (I _{Sink} = 100 μA)	V _{IH} V _{IL} V _H	2.55 2.55 0.03	2.71 2.65 0.06	2.80 2.80 -	V
RESET OUTPUT					
Output Sink Saturation ($V_{in} = 2.4 \text{ V}, I_{Sink} = 1.0 \text{ mA}$) ($V_{in} = 1.0 \text{ V}, I_{Sink} = 0.25 \text{ mA}$)	V _{OL}		0.14 0.1	0.4 0.3	V
Output Sink Current (V _{in} , Reset = 2.4 V)	I _{Sink}	6.0	12	30	mA
Output Off–State Leakage (V _{in} , Reset = 3.0 V) (V _{in} , Reset = 10 V)	^I R(leak)		0.02 0.02	0.5 1.0	μΑ
Clamp Diode Forward Voltage, Reset to Input Pin ($I_F = 5.0 \text{ mA}$)	V _F	0.6	0.9	1.2	V

TOTAL DEVICE

Operating Input Voltage Range	V _{in}	1.0 to 10	-	-	V
Quiescent Input Current $V_{in} = 3.0 V$ $V_{in} = 6.0 V$	l _{in}	-	9.0 24	15 40	μΑ

1. Maximum package power dissipation limits must be observed. 2. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible. 3. $T_{low} = 0^{\circ}$ C for MC34164 $T_{high} = +70^{\circ}$ C for MC34164

= -40°C for MC33164, NCV33164 = +125°C for MC33164, NCV33164

MC34164-5, MC33164-5 SERIES, NCV33164-5

ELECTRICAL CHARACTERISTICS (For typical values $T_A = 25^{\circ}C$, for min/max values T_A is the operating ambient temperature range that applies [Notes 5 & 6], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
COMPARATOR					
Threshold Voltage High State Output (V _{in} Increasing) Low State Output (V _{in} Decreasing) Hysteresis (I _{Sink} = 100 μA)	V _{IH} V _{IL} V _H	4.15 4.15 0.02	4.33 4.27 0.09	4.45 4.45 -	V
RESET OUTPUT					
Output Sink Saturation $(V_{in} = 4.0 \text{ V}, \text{ I}_{Sink} = 1.0 \text{ mA})$ $(V_{in} = 1.0 \text{ V}, \text{ I}_{Sink} = 0.25 \text{ mA})$	V _{OL}	-	0.14 0.1	0.4 0.3	V
Output Sink Current (V _{in} , Reset = 4.0 V)	I _{Sink}	7.0	20	50	mA
Output Off-State Leakage $(V_{in}, \overline{\text{Reset}} = 5.0 \text{ V})$ $(V_{in}, \overline{\text{Reset}} = 10 \text{ V})$	^I R(leak)	-	0.02 0.02	0.5 2.0	μΑ
Clamp Diode Forward Voltage, Reset to Input Pin ($I_F = 5.0 \text{ mA}$)	V _F	0.6	0.9	1.2	V
TOTAL DEVICE	•				•
Operating Input Voltage Range	V _{in}	1.0 to 10	-	-	V
Quiescent Input Current	l _{in}				μΑ

4. Maximum package power dissipation limits must be observed.

V_{in} = 5.0 V

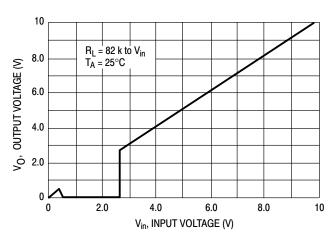
V_{in} = 10 V

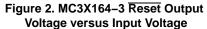
5. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.

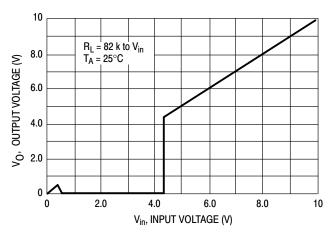
 \overline{T}_{high} = +70°C for MC34164 6. $T_{low} = 0^{\circ}C$ for MC34164

= -40°C for MC33164, NCV33164 = +125°C for MC33164, NCV33164

7. NCV prefix is for automotive and other applications requiring site and change control.







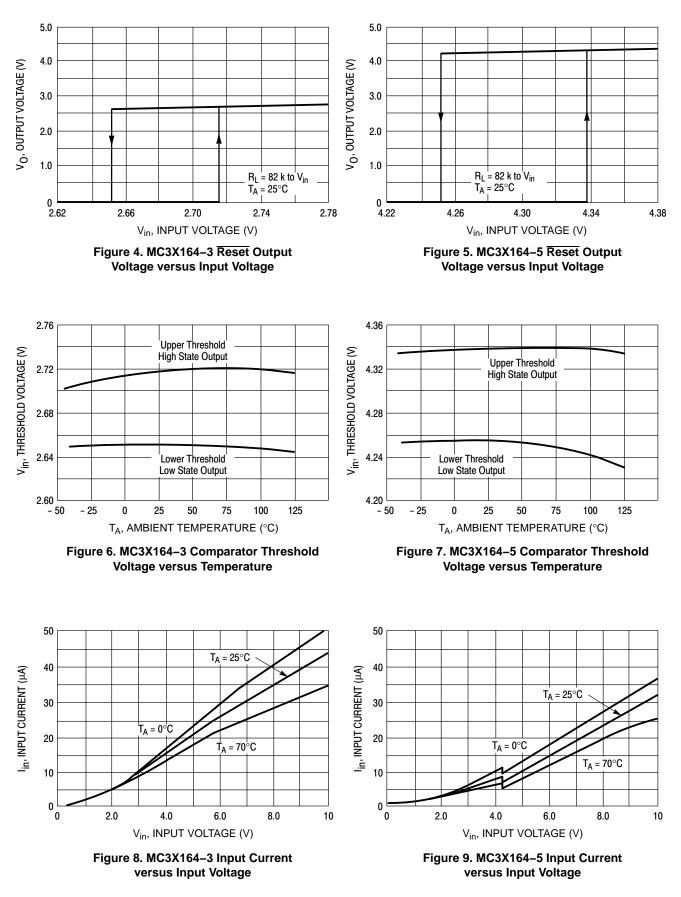
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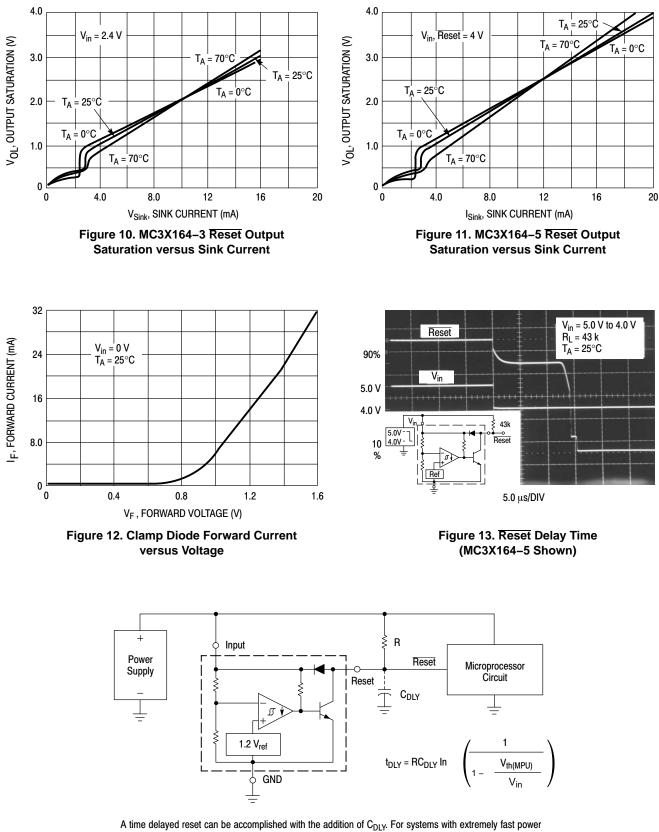
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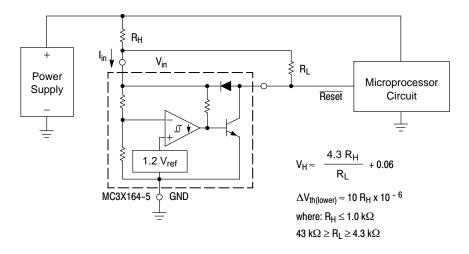
Figure 3. MC3X164-5 Reset Output Voltage versus Input Voltage





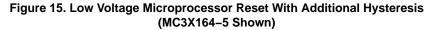
A time delayed reset can be accomplished with the addition of C_{DLY} . For systems with extremely fast power supply rise times (< 500 ns) it is recommended that the RC_{DLY} time constant be greater than 5.0 μ s. $V_{th(MPU)}$ is the microprocessor reset input threshold.

Figure 14. Low Voltage Microprocessor Reset



	Test Data						
V _H (mV)	∆V _{th} (mV)	R _Η (Ω)	R _L (kΩ)				
60	0	0	43				
103	1.0	100	10				
123	1.0	100	6.8				
160	1.0	100	4.3				
155	2.2	220	10				
199	2.2	220	6.8				
280	2.2	220	4.3				
262	4.7	470	10				
306	4.7	470	8.2				
357	4.7	470	6.8				
421	4.7	470	5.6				
530	4.7	470	4.3				

Comparator hysteresis can be increased with the addition of resistor R_H. The hysteresis equation has been simplified and does not account for the change of input current I_{in} as V_{in} crosses the comparator threshold (Figure 8). An increase of the lower threshold $\Delta V_{th(lower)}$ will be observed due to I_{in} which is typically 10 μ A at 4.3 V. The equations are accurate to \pm 10% with R_H less than 1.0 k Ω and R_L between 4.3 k Ω and 43 k Ω .



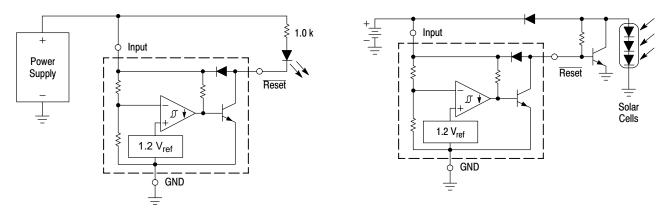


Figure 16. Voltage Monitor



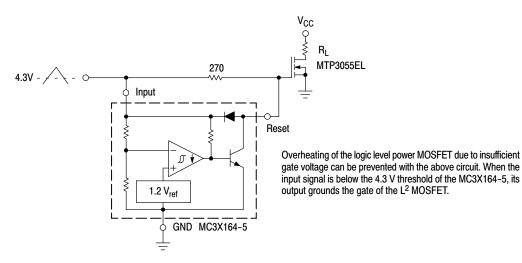


Figure 18. MOSFET Low Voltage Gate Drive Protection Using the MC3X164-5

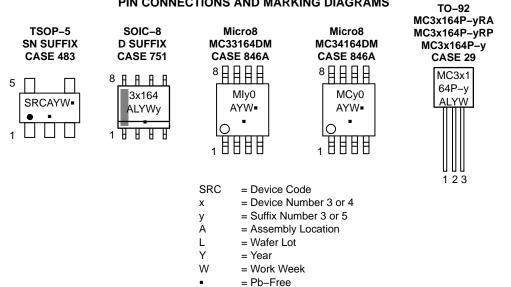
ORDERING INFORMATION

Device	Package	Shipping [†]
MC33164D-3G	SOIC-8 (Pb-Free)	98 Units / Rail
MC33164D-3R2G	SOIC-8 (Pb-Free)	2500 Unite / Tana & Deal
NCV33164D-3R2G*	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC33164DM-3R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC33164P-3G	TO–92 (Pb–Free)	2000 Units / Box
MC33164P-3RAG	TO–92 (Pb–Free)	2000 Units / Tape & Reel
MC33164P-3RPG	TO–92 (Pb–Free)	2000 Units / Pack
MC33164D-5G	SOIC-8 (Pb-Free)	98 Units / Rail
MC33164D-5R2G	SOIC-8 (Pb-Free)	
NCV33164D-5R2G*	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC33164DM-5R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC33164P-5G	TO–92 (Pb–Free)	2000 Units / Box
MC33164P-5RAG	TO–92 (Pb–Free)	2000 Units / Tape & Reel
MC33164P-5RPG	TO-92 (Pb-Free)	2000 Units / Pack
MC34164D-3G	SOIC-8 (Pb-Free)	98 Units / Rail
MC34164D-3R2G	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC34164DM-3R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC34164P-3G	TO–92 (Pb–Free)	2000 Units / Box
MC34164P-3RPG	TO–92 (Pb–Free)	2000 Units / Pack
MC34164D-5G	SOIC-8 (Pb-Free)	98 Units / Rail
MC34164D-5R2G	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC34164DM-5R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC34164SN-5T1G	TSOP-5 (Pb-Free)	3000 Units / Tape & Reel
MC34164P-5G	TO-92 (Pb-Free)	2000 Units / Box
MC34164P-5RAG	TO-92 (Pb-Free)	2000 Units / Tape & Reel
MC34164P-5RPG	TO-92 (Pb-Free)	2000 Units / Pack

*NCV33164: $T_{low} = -40^{\circ}C$, $T_{high} = +125^{\circ}C$. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

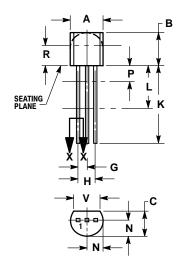
PIN CONNECTIONS AND MARKING DIAGRAMS

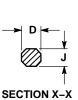


TO-92 (TO-226AA) **P** SUFFIX CASE 29-11 **ISSUE AM**

STRAIGHT LEAD

BULK PACK





BENT LEAD

TAPE & REEL AMMO PACK

D

SECTION X-X

J .

NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIN	IETERS
DIM	MIN	MAX
Α	4.45	5.20
В	4.32	5.33
С	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	
Ν	2.04	2.66
Р	1.50	4.00
R	2.93	
V	3.43	

R P Τ SEATING κ X G гС Ν

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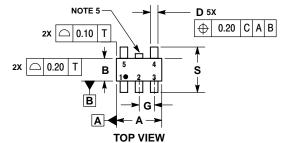
TSOP-5 **SN SUFFIX** CASE 483-02 ISSUE M

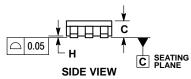
DETAIL Z

DETAIL Z

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS. SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A. 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY. MILLIMETERS

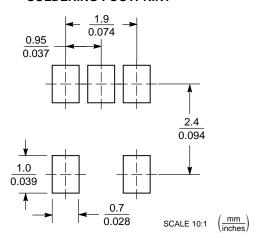
	MILLIMETERS						
DIM	MIN	MIN MAX					
Α	2.85	3.15					
В	1.35	1.65					
С	0.90	1.10					
D	0.25	0.50					
G	0.95	0.95 BSC					
н	0.01 0.10						
J	0.10	0.26					
к	0.20	0.60					
М	0 °	10 °					
S	2.50	3.00					





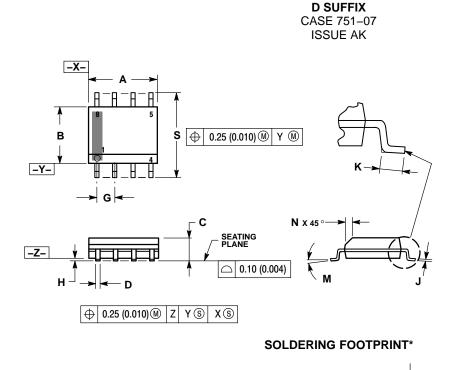
SOLDERING FOOTPRINT*

END VIEW



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOIC-8



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NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- PER SIDE. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION. 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07. 5.
- 6.

	MILLIMETERS		INC	CHES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	1.27 BSC		0 BSC	
н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
Κ	0.40	1.27	0.016	0.050	
м	0 °	8 °	0 °	8 °	
Ν	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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4.0

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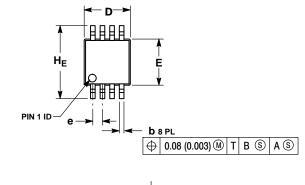
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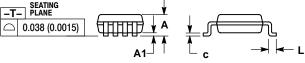
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SCALE 6:1

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Micro8 DM SUFFIX CASE 846A-02 **ISSUE J**





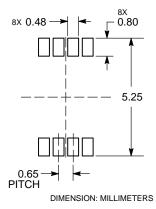
NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- DIMENSION A DOES NOT INCLUDE TER. DIMENSION A DOES NOT INCLUDE TER. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 3.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 4. 5.

846A-01 OBSOLETE, NEW STANDARD 846A-02.

	м	ILLIMETE	RS			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
С	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
е		0.65 BSC		0.026 BSC		
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199

RECOMMENDED SOLDERING FOOTPRINT*



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